NSN 5961-00-900-5519

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-900-5519 **Inclosure Material:** Metal **Overall Length:** 0.070 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.219 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.2 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**